About Trek: A Successful Company with Acknowledged Leadership Qualities

Founded on Technology

TREK, INC. was established in 1968 to serve the needs of the electrophotography industry for highly accurate, stable, costeffective measurement instrumentation and devices.



Novel probe design technology provided the foundation for the company's first electrostatic voltmeter, which quickly became the industry standard. Trek's design ensures highly accurate measurements under extreme conditions.

Growth through Innovation

In the decades that followed, Trek established itself as a designer and manufacturer of high quality instrumentation.

Innovative designs and unique solutions have fueled product development over the years. Trek developed the world's first allsolid-state, high-voltage, high-speed, DCstable amplifier, which is now the product of choice for medium-current ion implantation systems in semiconductor fabrication facilities around the world. As a result of Trek's close working relationship with its customers, new designs are constantly being created to answer the needs of industry and R&D.

Technical Expertise and Application Knowledge

Our scientifically based measurement expertise, coupled with our application knowledge, has enabled us to establish an enviable position in the markets we serve.

We are the experts when it comes to highly accurate measurement instruments and high voltage amplifiers, and the technology that drives them. Customers can depend on Trek to understand both the technical and practical aspects of an application. In many cases Trek is viewed as a virtual member of the customer's product development team.

Investing in the Future

In response to the needs of the marketplace, Trek recently established the Trek Technology Center in Lockport, NY as a facility for R&D and Engineering. In addition, a close working relationship with the nearby State University of New York at Buffalo assures that Trek has access to an extensive array of testing equipment and expertise to complement Trek's internal capabilities.



To enable future growth for the company, Trek's headquarters and manufacturing recently relocated to a refurbished 40,000 sq ft facility, also in Lockport.



Dedicated to Excellence

Trek has a well-respected reputation for excellence. We are the premier resource for electrostatic measurement and highvoltage solutions due to our product leadership and engineering excellence.

Committed to the Global **Marketplace**



Long before globalization was popular, TREK, INC. established Trek Japan KK in Tokyo, Japan for the purpose of providing sales, application engineering support and service to customers in Japan and elsewhere in the Pacific Rim region. A global sales and service network now exists enabling Trek to serve the needs of customers throughout the world.

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TREK - Experts in Electrostatic Measurement and High Voltage Power Amplifiers TREK, INC. 190 Walnut Street • Lockport, NY 14094 • 800-FOR TREK 716-438-7555 • 716-201-1804 (fax) • www.trekinc.com • sales@trekinc.com



Measurement and Power Solutions[™]



TREK, INC. **Precision Measurement of Electrostatic Voltage Enabled by Trek Electrostatic Voltmeter Instruments**

Novel Probe Design

Trek is an expert in utilizing technology to enable the precise measurement of electrostatic voltage and was the pioneer in noncontacting measurement methods for the electrophotography industry. A novel approach to probe design provided the foundation for the company's first electrostatic voltmeter, which quickly became the industry standard. Trek voltmeters, both then and now, utilize a design that ensures highly accurate measurements under extreme conditions, differentiating them from other products in the marketplace.



Model 341B Electrostatic Voltmeter

Capability Beyond Industry Norm

Trek's standard capabilities go well beyond the norm for others in this industry. What others call special, we call standard. Trek electrostatic voltmeters provide measurement ranges up to ± 20 kV, accuracies to the millivolt level, and speed of response to 50 microseconds for a 1 kV step. And Trek can go beyond what we call standard, to address application-specific requirements on a custom basis.

Ideal for Critical Operations

Trek's electrostatic voltmeters are ideally suited for use in critical operations associated with electrophotography, semiconductor, LCD and other processes where voltages need to be precisely measured and controlled for process optimization, or where charge accumulation (and electrostatic discharge events) pose a threat to production yields or product quality. By placing Trek's instruments on-line within a process, real time feedback and control is possible.

Product Innovations for the Future

Infinitron® Model 820



www.trekinc.com



Model 6000B-7C Probe

Performance in Diverse Applications

Trek noncontacting electrostatic voltmeter instruments are high performance devices that provide outstanding measurement speed and accuracy along with high surface resolution and no arc over. The voltmeter probes are designed to be less sensitive to dust particulates, enabling usage in diverse applications. Probe options include high temperature, high sensitivity, high resolution, transparent, miniature, and vacuumfriendly designs. Options also exist for probe aperture size, end/side view detection and body shape.



Model 370 Electrostatic Voltmeter

Trek's ultra-high impedance Infinitron[®] voltmeter technology advances the state of the art, enabling precision and accuracy when an application requires surface contact measurements with virtually zero charge exchange upon probe contact. This need for site-specific contacting measurement is taking on a greater importance as electronics are miniaturized, and other critical surface phenomena are being scrutinized.

Electrostatic Voltmeter Selection Table

ESVM Model	Output Voltage Range (DC or peak AC)	Speed of Response (10-90%) (less than)	Voltage Monitor Output Accuracy (better than)	Probe Models (order separately unless otherwise noted)	Special Features	
341B P0865	0 to ±20 kV 0 to ±10 kV	200 μs for a 1 kV step	±0.1% of full scale	3450 Standard 3453/3455 High-Temperature, High-Vacuum	High voltage, high speed	
370	0 to ±3 kV	50 μs for a 1 kV step	±0.05% of full scale	3800 Miniature 3870 High-Speed 7000 Standard	Optional data acquisition module	Electr of ph pro
370TR	0 to ±3 kV	200 µs for a 1 kV step	±0.05% of full scale	3629A Transparent 3627 Standard	Transparent probe option	
347	0 to ±3 kV	3 ms for a 1 kV step	±0.05% of full scale	6000B Standard/High Res 555P Miniature 6300 High-Temperature	Wide variety of probe options	c
344	0 to ±2 kV	3 ms for a 1 kV step	±0.05% of full scale	6000B Standard/High Res 555P Miniature 6300 High-Temperature	Wide variety of probe options	c
368A	0 to ±2 kV	200 μs for a 1 kV step	±0.1% of full scale	3800 Miniature 3870 High Speed	Multichannel enclosure	el
706B	0 to +1 kV or 0 to -1 kV (switch selectable)	DPM Sampling Rate: 3 readings/second	±0.5% of full scale	Side Viewing Probe (included)	Portable, durable, battery operated	m
323	0 to ±100 V	300 ms for a 100 V step	±0.05% of full scale	6000B Standard/High Res 555P Miniature 6300 High-Temperature	High sensitivity (5 mV), response speed control, noise/speed adjustments	
320C	0 to ±100 V	300 ms for a 100 V step	±0.05% of full scale	3250 High-Sensitivity	High sensitivity (1 mV), noise/speed adjustments	
325	0 to ±40 V	3 ms for a 10 V step	±0.05% of full scale	PD1216P High-Sensitivity	Low voltage, high sensitivity (1 mV), noise/speed adjustments	
The electrostatic voltmeters listed above utilize Trek's noncontacting technology. Trek's new Infinitron® technology permits contacting (and noncontacting) measurements with virtually zero charge						
800	0 to ±100 V	3.5 ms for a 100 V step	±0.1% of full scale	800P Contacting/Noncontacting Probe (included)	Infinitron [®] ultra-high impedance voltmeter: Resistance greater than 10 ¹⁶ Ω Capacitance less than 10 ⁻¹⁵ F	N
820	0 to ±2 kV	500 μs for a 1 kV step	±0.1% of full scale	820P Contacting/Noncontacting Probe (included)	Infinitron [®] ultra-high impedance voltmeter: Resistance greater than 10 ¹⁵ Ω Capacitance less than 10 ⁻¹⁵ F	N
821HH	0 to ±2 kV	500 μs for a 1 kV step	±1% of full scale	821P Contacting/Noncontacting Probe (included)	Infinitron [®] ultra-high impedance voltmeter: Resistance greater than 10 ¹⁴ Ω Capacitance less than 10 ⁻¹⁴ F	Hand



Typical Applications

Electrostatic research & development, charge accumulation monitoring of LCD production processes, monitoring surface potentials in electrostatic painting processes, electrostatic potential measurement on polymers, rubber, fabrics & paper

rophotographic research & development, research & development notoreceptors, charge accumulation monitoring in semiconductor oduction, measuring electrostatic potential on moving objects or surfaces, radiation effect studies

> Photosensitive surface studies, research & development

Photoconductor/dielectric surface voltage measurement, harge accumulation monitoring in semiconductor production, lectrostatic potential measurement on film, polymers & paper

Electrophotographic research & development, harge accumulation monitoring in semiconductor production, lectrostatic potential measurement on film, polymers & paper

Research & development applications, lectrostatic potential measurement on film, polymers & paper, electrophotographic research & development

Photoreceptor evaluations, materials testing, static charge neasurement for LCD, semiconductor, MR heads & IC processes

Semiconductor wafer surface voltage measurement, contact potential measurement, disk drive charge accumulation measurements

> Materials evaluation, electret studies, contact potential measurement

> Materials evaluation, electret studies, contact potential measurement

er transfer; refer to models below.

Neasurement of ESD-sensitive components and circuitry where virtually zero charge transfer is required

Aeasurement of ESD-sensitive components and circuitry where virtually zero charge transfer is required

-held unit for versatile measurement of ESD -sensitive components and circuitry where virtually zero charge transfer is required